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## KOREAN INTELLECTUAL PROPERTY OFFICE

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CO., LTD.

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## APPLICATION FOR PATENT

To the Commissioner of  
the Korean Intellectual Property Office

FILING DATE: October 4, 2002

TITLE: PHOTSENSITIVE RESIN COMPOSITION CONTROLLING  
SOLUBILITY AND PATTERN FORMATION METHOD OF DOUBLE-  
LAYER STRUCTURE USING THE SAME

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Submitted herewith is an application identified above pursuant to Article 42 of the Patent Act.

## **【ABSTRACT OF THE DISCLOSURE】**

### **【ABSTRACT】**

The present invention relates to a new photosensitive resin composition capable of solubility control and a pattern formation method of a double-layer structure using the same, and more particularly to a photosensitive resin composition that can control the  $\gamma$ -value using a new photopolymerization initiator and lower layer hardener and that can control a film thickness according to the exposure energy without pattern breakup, even with low exposure energy, which is useful for color filters and overcoating materials of LCD (liquid crystal display) manufacturing processes.

### **10 【REPRESENTATIVE FIGURE】**

FIG. 1

### **【KEY WORD】**

$\gamma$ -value, photopolymerization initiator, lower layer hardener, silt pattern, two-tone method

## **【SPECIFICATION】**

### **【TITLE OF THE INVENTION】**

PHOTOSENSITIVE RESIN COMPOSITION CONTROLLING SOLUBILITY AND  
PATTERN FORMATION METHOD OF DOUBLE-LAYER STRUCTURE USING THE  
5 SAME

### **【BRIEF DESCRIPTION OF THE DRAWINGS】**

Fig. 1 shows a two-tone structure on a color filter for applying a photosensitive  
resin composition of the present invention.

Fig. 2a, 2b, and 2c show the conventional Toray-type structure.

10 Fig. 3 shows the conventional Seiko-Epson-type structure.

Fig. 4 represents a slit mask pattern obtained by applying the two-tone method  
of the present invention.

The symbols represent the following: “1” is an organic film color filter layer  
(C/F layer); “2” is an organic film overcoat layer (O/C layer); “3” is a reflective portion  
15 reflective portion; “4” is a transmissive portion; “5” is a hole; “6” is a reflection  
window; “7” is a transmission window; and “8” is a transparent layer.

### **【DETAILED DESCRIPTION OF THE INVENTION】**

### **【OBJECT OF THE INVENTION】**

### **【FILED OF THE INVENTION AND DESCRIPTION OF THE RELATED ART】**

20 The present invention relates to a new photosensitive resin composition  
controlling solubility by hardness control and a pattern formation method of a double-  
layer structure using the same, and more particularly to a photosensitive resin  
composition that differentiates film thickness during developing of a photosensitive  
solution in an LCD (liquid crystal display) manufacturing process, which is useful for a  
25 double-layer structured color filter and overcoating material.

The conventional methods of forming color filters of liquid crystal displays are  
a dye method, a print method, an electrodeposition method, an ink-jet method, and a  
pigment dispersion method. Recently, the pigment dispersion method, which is  
advantageous in terms of pattern resolution and manufacturing, has been adopted.  
30 This method is applied for manufacturing LCDs of mobile phones, notebook computers,

monitors, and TVs.

Now, pigment-dispersed color compositions having more improved capabilities, not to mention the pattern resolution, are required. That is, the general pigment-dispersed color composition forms colored pixels by coating, exposing, and developing  
5 on the substrate. In this case, proper hardening of the exposed pixels makes them insoluble in the developing solution. For this reason, substantial exposure energy is required, and if the exposure energy is insufficient, the light (UV) does not fully reach until the lower layer of the coating film. Therefore, the hardness of the lower layer part becomes weak and pattern breakup occurs. Also, if the coating solution contains a lot  
10 of pigments or if the light blocking is excessive, the pattern breakup becomes intense and much higher exposure energy is required.

If the exposure energy is high, the developing solution does not dissolve the surface of the coating film at all, and the film thickness does not change after developing. On the other hand, if the exposure energy is low, the hardness of the  
15 lower layer becomes much lower, which decreases adhesion to the substrate and causes pattern breakup.

In general, the conventional photosensitive resin composition comprises a) a binder soluble in an alkaline solution; b) a crosslinking monomer having at least two ethylene double bonds; c) a pigment; d) a photopolymerization initiator; and e) a solvent.  
20 If necessary, it may include additives such as an enhancer for improving adhesion to the substrate, a stabilizer for improving storage stability, and a disperser for improving dispersion of pigments. Generally, this photosensitive resin composition reduces solubility to the developing solution during the developing process, by forming crosslinkages with crosslinking monomers due to radicals of photopolymerization  
25 initiators generated by the light. Here, the light blocking due to pigments causes differences in hardness of the upper layer and lower layer. That is, the hardness is lower at the lower layer. This can be the cause of film breakup or undercut by the reaction of the lower layer with the developing solution, if the exposure energy is low.

With variation of small-to-medium-sized device characteristics, differentiated  
30 characteristics are required. Formerly, with regard to optimization of the EMB

(embossing) process of reflectors for maximizing reflection efficiency of the reflection window, there was an attempt to solve the poor display characteristics in the portion in which there is no ambient light, which is a disadvantage of the reflective LCD, through a front-light, transfective LCD. The recent trend seems to follow the transfective LCD techniques, and the improvement of color filters in this regard is diversely in progress.

Among these, there is an attempt to expand the transmission window portion of the TFT-LCD, and thereby to increase color reproduction of the transmission window on the color filter and maximize reflectivity (transmissivity) rather than color reproduction of the reflective light.

Among these, with regard to change in chromaticity of the reflection window and the transmission window, there is an attempt to secure two tones on the color filter. Generally, securing two tones on the color filter means that the color filter characteristics of the transmission window and the reflection window are divided. With regard to difference of color characteristics of the reflection window and the transmission window, the basic problem is that the path of one is two times that of the other due to the difference of transreflection mode. In order to solve this problem, there are attempts to equalize optical properties of the transmission window and the reflection window by changing the optical property of the reflection window. Among these, there are the Toray method, which drills a hole on the reflection window and additively mixes light passing through the hole and the p.r region (Figs. 2a, 2b, and 2c), and the Seiko-Epson method which differentiates chromaticity of the transmission window and the reflection window using a change in thickness of the transparent organic insulation film (Fig. 3).

The Toray method secures a chromaticity difference by following the process represented by Figs. 2a, 2b, and 2c to cause a color difference of the transmission window and the reflection window. However, if the hole size is enlarged to maximize optical efficiency of the reflection window, the following process is affected, which is a problem with respect to controlling liquid crystal around the hole area. In applying an overcoat process to flatten the hole area, if the CF pattern is larger than  $1.0\mu\text{m}$ , the

display characteristics becomes unstable due to the instability of the PI print and rubbing processes.

In addition, the Seiko-Epson method secures a chromaticity difference by applying the structure of Fig. 3 to cause a color difference of the transmission window and the reflection window. However, an increase of the thickness of the transparent film is necessary to increase the color difference between the reflection window and the transmission window, which causes problems of cell gap and orientation of the liquid crystal.

#### 10    **【TECHNICAL SOLUTION TO BE SOLVED THE INVENTION】**

The present invention was made in consideration of the problems of the prior art, and it is an object of the present invention to provide a photosensitive resin composition capable of offering gradual solubility to a developing solution after unsaturated exposure due to hardness graduations from the lower layer to the upper layer without regard to the film thickness, and capable of preventing film breakup and undercut through chemical bonding of the substrate and the resin composition.

It is another object of the present invention to provide a photosensitive resin composition capable of forming a film with varying thickness in a single exposure step by exposing with a mask capable of controlling transmissivity and developing the partially hardened resin composition to have variable thickness from the upper layer of the film.

#### 20    **【CONSTITUTIONS OF THE INVENTION】**

In order to achieve the objects, the present invention provides a photosensitive resin composition for a color filter comprising:

- 25        a) 5 to 30 parts by weight of binder soluble in an alkaline solution;
- b) 5 to 30 parts by weight of a crosslinking monomer having at least two ethylene double bonds;
- c) 10 to 60 parts by weight of a pigment;
- d) 1 to 5 parts by weight of one or more photopolymerization initiators selected
- 30    from the group consisting of an acetophenone compound, a xanthone compound, a



benzoin compound, and an imidazole compound;

e) 0.1 to 2 parts by weight of one or more lower layer hardeners selected from the group consisting of silane polymer, and an ethylene monomer having at least one epoxy group or an oligomer thereof; and

5 f) 20 to 80 parts by weight of a solvent.

Furthermore, the present invention provides a method of double-layer pattern formation comprising steps of exposing and developing a film coated with said color filter photosensitive resin composition using a slit mask.

## 10 **DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS**

The present invention will now be explained in more detail.

The present invention is characterized by offering a photosensitive resin composition for a color filter capable of forming a film with varying thickness in a single exposure process, by forming a complete pattern at a portion where the light is  
15 fully transmitted and offering a thinner film thickness without pattern breakup during developing at a portion where less light is transmitted, by using a slit mask designed to control transmission of exposure light.

In an alkali-soluble photosensitive resin composition for a color filter of the present invention, the binder soluble in an alkaline solution (a) is a copolymer of  
20 monomers having ethylene acidic groups and monomers having no ethylene acidic groups in the polymer chain.

For the monomers having ethylene acidic groups, there are acrylic acid, methacrylic acid, itaconic acid, maleic acid, fumaric acid, vinyl acetic acid, acid anhydrides thereof, 2-acryloxyethylhydrogen phthalate, 2-acryloxypropylhydrogen  
25 phthalate, and 2-acryloxypropylhexahydrogen phthalate. The content of the monomers having ethylene acidic groups is preferably 10 to 40wt%, and more preferably 20 to 30wt%. If the content is below 10wt%, the solubility of the photosensitive resin composition to the alkaline developing solution decreases. Otherwise, if it exceeds 40wt%, pattern falling-off and breakup may occur during developing.

30 For the monomers having no acidic groups, there are isobutyl acrylate, *tert*-

butyl acrylate, lauryl acrylate, alkyl acrylate, steacrylate, cyclohexyl acrylate, isobonyl acrylate, benzyl acrylate, 2-hydroxy acrylate, trimethoxybutyl acrylate, ethylcarbido acrylate, phenoxyethyl acrylate, 4-hydroxybutyl acrylate, phenoxypolyethyleneglycol acrylate, 2-hydroxyethyl acrylate, 2-hydroxypropyl acrylate, 2-acryloxyethyl-2-hydroxypropyl phthalate, 2-hydroxy-3-phenoxypropyl acrylate and methacrylates thereof; acrylates having halogen atoms such as 3-fluoroethyl acrylate and 4-fluoropropyl acrylate, and methacrylates thereof; acrylates having siloxane groups such as triethylsiloxylethyl acrylate and methacrylates thereof; and aromatic olefins such as styrene and 4-methoxystyrene. These compounds can be used alone or in combination.

10 The content of the monomers having no acidic groups in the polymer composition is preferably 60 to 90wt%, and more preferably 65 to 85wt%. If the content is below 60wt%, adhesivity to the glass substrate decreases during developing, so that the pattern breakup becomes intense and the pattern linearity worsens. Otherwise, if it exceeds 90wt%, the developing time increases.

15 The content of the binder soluble dissolved in an alkaline solution is preferably 5 to 30 parts by weight based on the total photosensitive resin composition.

In the photosensitive resin composition of the present invention, for the crosslinking monomer having at least two ethylene double bonds (b), there are 1,4-butanediol diacrylate, 1,3-butyleneglycol diacrylate, ethyleneglycol diacrylate, 20 pentaerythritol tetraacrylate, triethyleneglycol diacrylate, polyethyleneglycol diacrylate, dipentaerythritol diacrylate, sorbitol triacrylate, bisphenol A diacrylate derivatives, trimethylpropane triacrylate, dipentaerythritolpoly acrylate, and methacrylates thereof. The content of the crosslinking monomer having at least two ethylene double bonds is preferably 5 to 30 parts by weight, and more preferably 5 to 20 parts by weight, based on the total photosensitive resin composition. If the content is below 5 parts by weight, 25 pattern formation is difficult due to the low hardness. Otherwise, if it exceeds 30 parts by weight, excessive hardness causes pattern breakup during developing and worsens pattern linearity.

In the photosensitive resin composition of the present invention, organic 30 pigment or inorganic pigment can be used for the pigment (c). Specific examples of

organic pigments are C.I. pigment yellow 83, C.I. pigment yellow 150, C.I. pigment yellow 138, C.I. pigment yellow 128, C.I. pigment orange 43, C.I. pigment red 177, C.I. pigment red 202, C.I. pigment red 209, C.I. pigment red 254, C.I. pigment red 255, C.I. pigment green 7, C.I. pigment green 36, C.I. pigment blue 15, C.I. pigment blue 15:3, C.I. pigment blue 15:4, C.I. pigment blue 15:6, C.I. pigment violet 23, C.I. pigment black 1, and C.I. pigment black 7. For inorganic pigments, there are titanium oxide, titanium black, and carbon black. These pigments can be used alone or in combination. The content of the pigment is preferably 10 to 60 parts by weight, based on the total photosensitive resin composition.

In particular, in the photosensitive resin composition of the present invention, the photopolymerization initiator (d) is a compound that can initiate polymerization of the crosslinking monomer in the wavelength range of visible, UV, and far UV. As mentioned above, one or more compounds selected from the group consisting of an acetophenone compound, a xanthone compound, a benzoin compound, and an imidazole compound can be used for the photopolymerization initiator.

Specific examples of the acetophenone compounds are benzophenone, *p*-(diethylamino)benzophenone, 2,2-dichloro-4-phenoxyacetophenone, 2,2-diethoxyacetophenone, 2,2-dibutoxyacetophenone, 2-hydroxy-2-methylpropiophenone, and *p-t*-butyltrichloroacetophenone. Specific examples of the xanthone compounds are xanthone, thioxanthone, 2-methylthioxanthone, 2-isobutylthioxanthone, 2-dodecylthioxanthone, and 2,4-dimethylthioxanthone. Specific examples of the benzoin compounds are benzoin, benzoyl ethyl ether, benzoyl methyl ether, benzoyl propyl ether, and *t*-butyl benzoyl ether. And specific examples of the imidazole compounds are 2,2-bis-2-chlorophenyl-4,5,4,5-tetraphenyl-2-1,2-biimidazole, and 2,2-bis(2,4,6-tricyanophenyl)-4,4,5,5-tetraphenyl-1,2-biimidazole.

The photopolymerization initiator can be used together with a sensitizer or a hardening promoter, such as 4-dimethylaminobenzophenone, isopropylthioxantone, methyl-*o*-benzoyl benzoate, 4-(methylphenylthio)-phenyl-phenylmethane, 2,4-diethylthioxantone, 2-chlorothioxantone, benzophenone, ethylanthraquinone, and 2-mercaptobenzoxazole, if required.

The content of the photopolymerization initiator is preferably 0.5 to 5 parts by weight, and more preferably 1 to 2 parts by weight, based on the total photosensitive resin composition. If the content is below 0.5 parts by weight, pattern formation becomes difficult, and the pattern linearity worsens due to low sensitivity. Otherwise, if it exceeds 5 parts by weight, there may be problems of storage stability, severe pattern breakup during developing due to high hardness, and residue generation in the region outside the pattern.

In the photosensitive resin composition of the present invention, the lower layer hardener (e) is used to increase hardness of the lower layer. For the lower layer hardener, it is preferable to use one or more compounds selected from the group consisting of a silane polymer, an ethylene monomer having at least one epoxy group, and an oligomer thereof. Typical examples of the silane polymer are vinyltrimethoxysilane, vinyltriethoxysilane, vinyltris(2-methoxyethoxy)silane, 3-aminopropyltriethoxysilane, 3-acryloxypropyltrimethoxysilane, 3-glycidylpropyltrimethoxysilane, 3-glycidylpropyltrimethoxysilane, 3-glycidylpropylmethyldimethoxysilane, 2-(3,4-ethoxycyclohexyl)ethyltrimethoxysilane, 3-chloropropyltrimethoxysilane, and 3-methacrylopropyltrimethoxysilane. These compounds can be use alone or in combination.

For the ethylene monomer having at least one epoxy group or oligomer thereof, there are monomers such as glycidyl acrylate, glycidyl methacrylate, glycidylethyl acrylate, glycidylethyl methacrylate, glycidylpropyl acrylate, glycidylpropyl methacrylate, 3,4-epoxybutyl methacrylate, and 6,7-epoxybutyl acrylate, and oligomers thereof. These compounds can also be use alone or in combination.

The content of the lower layer hardener is preferably 0.1 to 2 parts by weight, and more preferably 0.1 to 1 parts by weight, based on the total photosensitive resin composition. If the content is below 0.1 parts by weight, pattern breakup occurs due to low hardness of the lower layer and poor adhesion to the substrate. Otherwise, if it exceeds 2 parts by weight, residue may remain because the developing rate of the unexposed portion becomes very low.

In the photosensitive resin composition of the present invention, the solvent (f)

is determined by solubility, pigment dispersivity, and coatability. Specifically, ethyleneglycol monomethyl ether acetate, propyleneglycol monomethyl ether, propyleneglycol methyl ether acetate, propyleneglycol monoethyl ether acetate, diethyleneglycol dimethyl ether, diethyleneglycol methylethyl ether, cyclohexanone, 3-methoxyethyl propionate, 3-ethoxymethyl propionate, and 3-ethoxyethyl propionate are preferable. These compounds can be used alone or in combination. The content of the solvent is preferably 20 to 80 parts by weight based on the total photosensitive resin composition.

Also, the photosensitive resin composition of the present invention can further comprise a (g) disperser for improving dispersivity of the pigment or an additive for improving coatability. For example, a polyester disperser, a polyurethane disperser, a silicon surfactant, or a fluorine surfactant can be used at 0.01 to 1 parts by weight based on the total photosensitive resin composition.

Also, the present invention can form a double-layer pattern using the photosensitive resin composition. Fig. 1 shows an embodiment example that is applied the photosensitive resin composition of the present invention to a mask.

In the present invention, the double-layer pattern formation is performed by applying the coating solution containing pigments on a transparent substrate and removing solvent remaining on the coating film by prebaking. If the coated film is exposed through a mask having a slit pattern, the optical hardness of the pattern portion, the slit portion, and the unexposed portion become different due to differences of exposure energy. The slit portion receives less exposure energy, and the partial hardening offers partial solubility during developing.

For this purpose, the present invention applies the two-tone method on the color filter to maximize optical efficiency of the chromaticity change in the reflection window and the transmission window and to solve the problem of the conventional slit structure. The two-tone method utilizes exposure energy. That is, the optical property is divided according to the film thickness by differentiating the exposure at the transmission window and the reflection window. The present invention is a different version of differentiating thickness of the reflection window and the transmission window in order

to respond to the requirement of more than two times the color difference between the reflection window and the transmission window. Accordingly, the present invention can solve the problems of the conventional Toray and Seiko-Epson methods more effectively when obtaining more than ½ tone characteristics as an expansion of the tow-  
5 tone method by differentiating the exposure energy.

That is, while the conventional methods secure the same thickness of the reflection window in the two-tone layer, the present invention partially removes the color layer through slit tone design control, as shown in Fig. 1. The color filter structure of the present invention differentiates thickness of the slit portion using bars  
10 and spaces of the slit, and removes a color portion (color p.r) due to the exposure energy, which prevents optical filtering and lets the light reflect. Therefore, change in liquid crystal display characteristics can be minimized by reducing film thickness differences of the transmission window. This utilizes the fact that if the film thickness difference and the pattern gap become smaller, the flattening ratio of the overcoat (O/C) film  
15 becomes higher. This structure uses color difference due to the film thickness and mixes color by adding light from the reflection window and from the unfiltered portion inside the reflection window, and is a combination of the Toray method and the two-tone method.

This feature requires color sense calculation per area and optimization of  
20 prediction techniques. However, it can be realized when applied to a slit mask design having identical optical density on a plane while having less light at a specific portion, such as Split-6 (Fig. 4).

The slit of the photomask comprises a light-passing portion (WL) and a light-  
blocked portion (BS). The distance of the light-passing portion and the light-blocked  
25 portion can be designed to be 1 to 100μm in x- and y-axes. Also, the slit of the photomask may have a polygonal pattern having a lattice or curvature in one direction (x- or y-axis) or both directions (x- and y-axes). By changing the area of the light-passing portion and the light-blocked portion, it can be controlled to absorb 10 to 90% of the exposure energy. To be specific, the slit mask has a slit pattern wherein widths  
30 of the light-passing portion (WL) and the light-blocked portion (BS) are 1 to 100μm in

x- and y-axes. Also, the slit mask has a lattice pattern wherein widths of the light-passing portion (WL) and the light-blocked portion (BS) are 1 to 100 $\mu$ m in x- and y-axes.

As mentioned above, unsaturated exposure at the slit portion causes partial  
5 hardening and gradual dissolution during developing.

At the upper layer of the film, the reaction of oxygen in the air with the initiator interrupts the initiation reaction, which reduces hardness and increases solubility to the developing solution. The photopolymerization initiator used in the present invention offers the same hardness to the middle layer and lower layer of the film. The lower  
10 layer hardener increases hardness of the lower layer of the film through chemical bonding of the organic composition and the substrate, and causes a solubility difference between the upper layer, middle layer, and lower layer of the film, which offers a gradual difference in film thickness during developing.

The photosensitive composition according to the present invention is  
15 invulnerable to film breakup during developing even with a small exposure energy, and it does not cause a rapid thickness reduction. Accordingly, the  $\gamma$ -value, which is the change of film thickness according to the exposure energy, decreases, and therefore the thickness of the double-layer structure can be controlled.

The  $\gamma$ -value of the photosensitive composition according to the present  
20 invention is preferably below 2.5. More preferably, the  $\gamma$ -value is 0.1 to 2.5. In this case, the film thickness can be reduced to 5 to 90% depending on the exposure energy. More preferably, the  $\gamma$ -value of the photosensitive composition of the present invention is 0.5 to 1.0. In this case, the film thickness can be reduced to 20 to 80%, and the developing margin according to the developing time is best.

25 For the developing solution used in the developing process, any common alkaline developing solution can be used. Preferably used are a diluted inorganic alkaline aqueous solution such as a potassium hydroxide aqueous solution, a sodium hydroxide aqueous solution, a sodium carbonate aqueous solution, and a potassium carbonate aqueous solution; and an alkaline solution including amines such as a  
30 triethanolamine aqueous solution, a trimethylamine aqueous solution, and a

tetramethylammonium hydroxide aqueous solution. In general, the developing is performed by a spray method used in LCD processes. However, the dipping method also can be used, and the pattern is formed by the curing process after developing.

Hereinafter, the present invention is described in more detail through Examples and Comparative Examples. However, the following Examples and Comparative Examples are for the understanding of the present invention, and the present invention is not limited to the following Examples. In the following Examples, the percentage and mixing ratio are based on weight, unless stated otherwise.

[Example 1]

10 A liquid photosensitive composition was prepared by mixing: 20 parts by weight of a copolymer of styrene/methacrylic acid/butyl methacrylate (copolymerization ratio = 60/20/20; weight-average molecular weight = 30,000) as the binder soluble in an alkaline solution (a); 8 parts by weight of dipentaerythritolhexaacrylate as the crosslinking monomer having at least two ethylene  
15 double bonds (b); 20 parts by weight of C.I. pigment red 254 and 10 parts by weight of C.I. pigment yellow 139 as the pigment (c); 1 parts by weight of Irgacure369 (Shiba Specialty Chemical) and 1 parts by weight of 4,4'-bisdiethylaminobenzophenone as the photopolymerization initiator (d); 0.1 parts by weight of 3-acryloxypropyltrimethoxysilane (Shin Etsu) as the lower layer hardener (e); and 28  
20 parts by weight of propyleneglycolmethyl ether acetate and 10 parts by weight of cyclohexanone as the solvent (f).

[Example 2]

A photosensitive resin composition was prepared by the same composition and content of Example 1, except that 1 parts by weight of Irgacure907 (Shiba Specialty  
25 Chemical) as the photopolymerization initiator (d) and 0.05 parts by weight of vinyltriethoxysilane as the lower layer hardener (e) were used.

[Example 3]

A photosensitive resin composition was prepared by the same composition and content of Example 1, except that 1 parts by weight of Irgacure369 (Shiba Specialty  
30 Chemical) and 1 parts by weight of isopropylthioxantone as the photopolymerization



initiator (d) and 0.2 parts by weight of 3,4-epoxybutyl methacrylate as the lower layer hardener (e) were used.

[Example 4]

A photosensitive resin composition was prepared by the same composition and  
5 content of Example 1, except that 20 parts by weight of C.I. pigment green 36 and 10 parts by weight of C.I. pigment yellow 150 as the pigment (c) and 0.2 parts by weight of 3-acryloxypropyltrimethoxysilane (Shin Etsu) as the lower layer hardener (e) were used.

[Example 5]

A photosensitive resin composition was prepared by the same composition and  
10 content of Example 1, except that 20 parts by weight of C.I. pigment blue 15:6 as the pigment (c), 1 parts by weight of Irgacure369 (Shiba Specialty Chemical) and 1 parts by weight of 2,4-diethylthioxantone as the photopolymerization initiator (d), and 0.2 parts by weight of 3-acryloxypropyltrimethoxysilane (Shin Etsu) as the lower layer hardener (e) were used.

15 [Comparative Example 1]

A photosensitive resin composition was prepared by the same composition and content of Example 1, except that 2wt% of 2,4-bis(trichloromethyl)-6-p-methoxystyryl-s-triazine as the photopolymerization initiator (d) was used, and the lower layer hardener (e) was not used.

20 [Comparative Example 2]

A photosensitive resin composition was prepared by the same composition and content of Example 1, except that 20 parts by weight of C.I. pigment green 36 and 10 parts by weight of C.I. pigment yellow 150 as the pigment (c), 2 parts by weight of 2,4-bis(trichloromethyl)-6-p-methoxystyryl-s-triazine as the photopolymerization initiator (d),  
25 and 0.2 parts by weight of 6,7-epoxybutyl acrylate as the lower layer hardener (e) were used.

[Comparative Example 3]

A photosensitive resin composition was prepared by the same composition and content of Example 1, except that 30 parts by weight of C.I. pigment blue 15:6 as the  
30 pigment (c) and 1 parts by weight of Irgacure369 (Shiba Specialty Chemical) and 1

parts by weight of 4,4'-bisdiethylaminobenzophenone as the photopolymerization initiator (d) were used, and the lower layer hardener (e) was not used.

【Table 1】

	Lower layer hardener	Photoinitiator		
		Triazine	Acetophenone compound	Sensitizer
Example 1	0.05	-	1	1
Example 2	0.05	-	1	-
Example 3	0.2	-	1	1
Example 4	0.2	-	1	1
Example 5	0.2	-	1	1
Comp. Example 1	-	2	-	-
Comp. Example 2	0.2	2	-	-
Comp. Example 3	-	-	1	1

#### Comparison of Developing Characteristics

5 For the photosensitive compositions of Examples 1 to 5 and Comparatives Example 1 to 3, developing characteristics according to the kinds and contents of the photopolymerization initiator and the lower layer hardener were compared.

Each photosensitive composition prepared in the above Examples and Comparative Examples was spin-coated on a glass substrate at a thickness of 1μm, and  
10 dried on an 80□ hot plate for 2 min to obtain a coating film.

Then, after positioning a photomask on the film, about 100 to 200mj/cm<sup>2</sup> of exposure was carried out with a 365nm wavelength light using a superhigh-pressure mercury lamp with a wavelength of 200nm to 400nm. Then, the film was developed with a spray nozzle using a KOH developing solution (Dongjin Semichem; DCD-  
15 260CF). For the developed fine pattern, the thickness of the exposed portion and the slit portion was determined to evaluate the developing characteristics. The results are shown in Table 2. To determine a solubility difference between the exposed portion and unexposed portion to the developing solution, graphs showing the thickness change according to the exposure energy (Fig. 2 and Fig. 3) were prepared, and the γ-values  
20 were calculated from the slope. The results are shown in Table 3.

【Table 2】

Thickness after Developing ( $\mu\text{m}$ )

	Exposure energy ( $\text{mj}/\text{cm}^2$ )	Developing time (s)		
		60	80	100
Example 1	200	1.00	1.00	1.00
	100	1.00	0.99	0.98
	20	0.3	0.3	-
Example 2	200	1.00	1.00	1.00
	100	0.99	0.80	0.50
	20	0.30	-	-
Example 3	200	1.00	1.00	1.00
	100	0.99	0.98	0.98
	20	0.61	0.56	0.56
Example 4	200	1.00	1.00	1.00
	100	0.97	0.97	0.95
	20	0.55	0.50	0.48
Example 5	200	1.00	1.00	1.00
	100	0.85	0.73	0.60
	20	0.45	0.43	0.41
Comp. Example 1	200	1.00	1.00	1.00
	100	1.00	0.98	0.98
	20	-	-	-
Comp. Example 2	200	1.00	1.00	1.00
	100	0.99	1.00	0.4
	20	-	-	-
Comp. Example 3	200	1.00	1.00	1.00
	100	1.00	1.00	0.2
	20	-	-	-

【Table 3】

	$\gamma$ -Value
Example 1	1.3
Example 2	2.5
Example 3	0.9
Example 4	0.8
Example 5	1.1
Comparative Example 1	3.4
Comparative Example 2	3.5
Comparative Example 3	4.0

As shown in Table 3,  $\gamma$ -values of the present invention (Examples 1 to 5) are all low (0.8 to 2.5), and therefore no film breakup occurred during developing even with a low exposure energy, and there were no rapid reductions of film thickness.

5     **【EFFECTS OF THE INVENTION】**

As explained above, the photosensitive resin composition according to the present invention can control the  $\gamma$ -value using a new photopolymerization initiator and lower layer hardener. Also, film thickness control according to the exposure energy is possible because the upper layer dissolves without pattern breakup, even with low

10    exposure energy.

**【SCOPES OF PATENT CLAIM】**

**【CLAIM 1】**

1. A photosensitive resin composition for a color filter comprising:
  - a) 5 to 30 parts by weight of a binder soluble in an alkaline solution;
  - 5        b) 5 to 30 parts by weight of a crosslinking monomer having at least two ethylene double bonds;
  - c) 10 to 60 parts by weight of pigment;
  - d) 1 to 5 parts by weight of one or more photopolymerization initiators selected from the group consisting of an acetophenone compound, a xanthone compound, a benzoin compound, and an imidazole compound;
  - 10        e) 0.1 to 2 parts by weight of one or more lower layer hardeners selected from the group consisting of a silane polymer, and an ethylene monomer having at least one epoxy group or oligomer thereof; and
  - f) 20 to 80 parts by weight of a solvent.

15        **【CLAIM 2】**

The photosensitive resin composition for a color filter according to Claim 1, wherein the binder soluble in an alkaline solution is a copolymer of 10 to 40wt% of monomers having ethylene acidic groups and 60 to 90wt% of monomers having no ethylene acidic group.

20        **【CLAIM 3】**

The photosensitive resin composition for a color filter according to Claim 2, wherein the monomers having ethylene acidic groups are selected from the group consisting of acrylic acid, methacrylic acid, itaconic acid, maleic acid, fumaric acid, vinyl acetic acid, and acid anhydrides thereof, and 2-acryloxyethylhydrogen phthalate, 2-acryloxypropylhydrogen phthalate, and 2-acryloxypropylhexahydrogen phthalate

25        **【CLAIM 4】**

The photosensitive resin composition for a color filter according to Claim 2, wherein the monomers having no ethylene acidic group are selected from the group consisting of isobutyl acrylate, *tert*-butyl acrylate, lauryl acrylate, alkyl acrylate, steacrylate, cyclohexyl acrylate, isobonyl acrylate, benzyl acrylate, 2-hydroxy acrylate,

30

trimethoxybutyl acrylate, ethylcarbidiol acrylate, phenoxyethyl acrylate, 4-hydroxybutyl acrylate, phenoxypolyethyleneglycol acrylate, 2-hydroxyethyl acrylate, 2-hydroxypropyl acrylate, 2-acryloxyethyl-2-hydroxypropyl phthalate, 2-hydroxy-3-phenoxypropyl acrylate, and methacrylates thereof; acrylates having a halogen atom and  
5 methacrylates thereof; acrylates having a siloxane group and methacrylates thereof; and aromatic olefins.

**【CLAIM 5】**

The photosensitive resin composition for a color filter according to Claim 1, wherein the crosslinking monomer having at least two ethylene double bonds is one or  
10 more compounds selected from the group consisting of 1,4-butanediol diacrylate, 1,3-butyleneglycol diacrylate, ethyleneglycol diacrylate, pentaerythritol tetraacrylate, triethyleneglycol diacrylate, polyethyleneglycol diacrylate, dipentaerythritol diacrylate, sorbitol triacrylate, bisphenol A diacrylate derivatives, trimethylpropane triacrylate, dipentaerythritolpoly acrylate, and methacrylates thereof.

15 **【CLAIM 6】**

The photosensitive resin composition for a color filter according to Claim 1, wherein the pigment is an organic pigment or an inorganic pigment.

**【CLAIM 7】**

The photosensitive resin composition for a color filter according to Claim 1,  
20 wherein the solvent is one or more compounds selected from the group consisting of ethyleneglycol monomethyl ether acetate, propyleneglycol monomethyl ether, propyleneglycol methyl ether acetate, propyleneglycol monoethyl ether acetate, diethyleneglycol dimethyl ether, diethyleneglycol methylethyl ether, cyclohexanone, 3-methoxyethyl propionate, 3-ethoxymethyl propionate, and 3-ethoxyethyl propionate.

25 **【CLAIM 8】**

The photosensitive resin composition for a color filter according to Claim 1, wherein the ethylene monomer having at least one epoxy group or oligomer thereof is one or more compounds selected from the group consisting of glycidyl acrylate, glycidyl methacrylate, glycidylethyl acrylate, glycidylethyl methacrylate,  
30 glycidylpropyl acrylate, glycidylpropyl methacrylate, 3,4-epoxybutyl methacrylate, 6,7-

epoxybutyl acrylate, and oligomers thereof.

**【CLAIM 9】**

The photosensitive resin composition for a color filter according to Claim 1, which further comprises:

- 5           g) 0.01 to 1 parts by weight of a disperser for improving dispersion of the pigment and an additive for improving coatability, which is one or more compounds selected from the group consisting of a polyester disperser, a polyurethane disperser, a silicon surfactant, and a fluorine surfactant.

**【CLAIM 10】**

- 10           The photosensitive resin composition for a color filter according to Claim 1, whose developing  $\gamma$ -value is 0.1 to 2.5.

**【CLAIM 11】**

- 15           A double-layer pattern formation method using a slit mask, wherein the photosensitive resin composition for a color filter according to Claim 1 is exposed and developed with the slit mask.

**【CLAIM 12】**

A double-layer pattern formation method using a slit mask according to Claim 11, wherein the slit mask has a slit pattern wherein the width of the light-passing portion (WL) is 1 to 100 $\mu$ m in x- and y-axes.

- 20           **【CLAIM 13】**

A double-layer pattern formation method using a slit mask according to Claim 11, wherein the slit mask has a slit pattern wherein the width of the light-blocked portion (BS) is 1 to 100 $\mu$ m in x- and y-axes.

**【CLAIM 14】**

- 25           A double-layer pattern formation method using a slit mask according to Claim 11, wherein the slit mask has a lattice pattern wherein the width of the light-passing portion (WL) is 1 to 100 $\mu$ m in x- and y-axes.

**【CLAIM 15】**

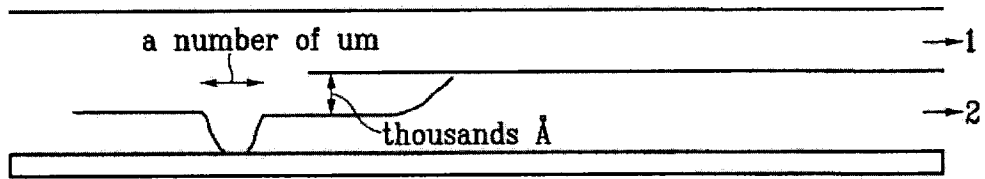
- 30           A double-layer pattern formation method using a slit mask according to Claim 11, wherein the slit mask has a lattice pattern wherein the width of the light-blocked

portion (BS) is 1 to 100 $\mu\text{m}$  in x- and y-axes.



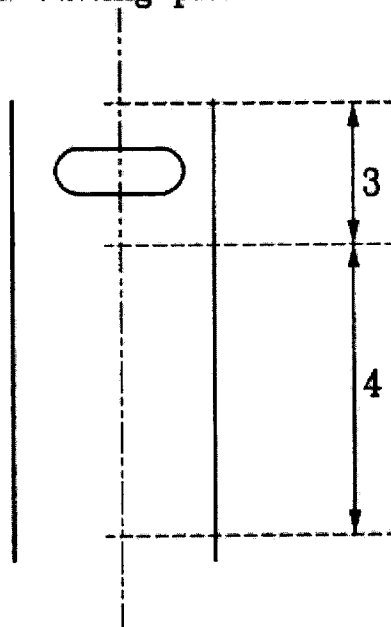
【FIGURES】

【FIG. 1】



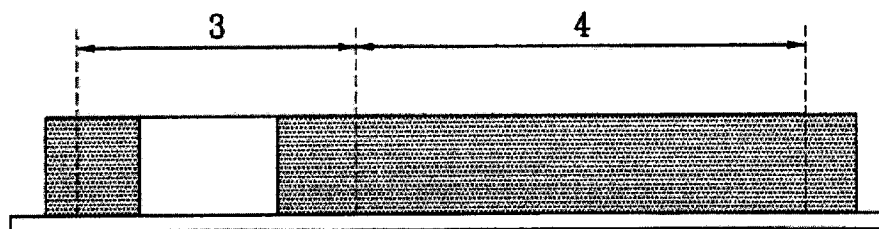
【FIG. 2a】

a cutting plane

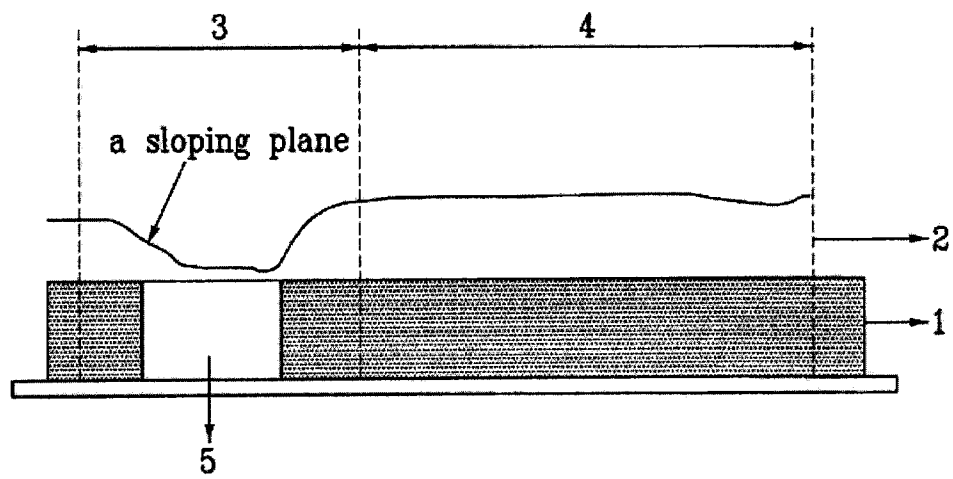


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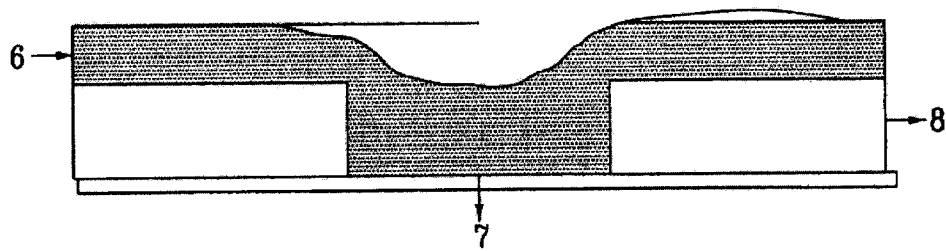
【FIG. 2b】



【FIG. 2c】



【FIG. 3】



【FIG. 4】

